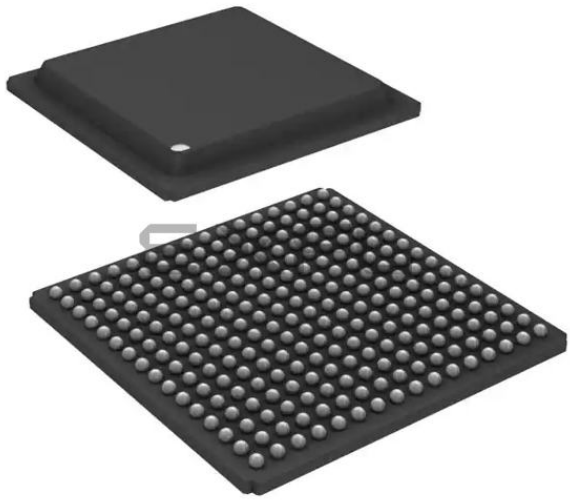

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	MPC8xx
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	50MHz
Co-Processors/DSP	Communications; CPM
RAM Controllers	DRAM
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	3.3V
Operating Temperature	0°C ~ 95°C (TA)
Security Features	-
Package / Case	256-BBGA
Supplier Device Package	256-PBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc850dezq50bur2

The CPM of the MPC850 supports up to seven serial channels, as follows:

- One or two serial communications controllers (SCCs). The SCCs support Ethernet, ATM (MPC850SR and MPC850DSL), HDLC and a number of other protocols, along with a transparent mode of operation.
- One USB channel
- Two serial management controllers (SMCs)
- One I^2C port
- One serial peripheral interface (SPI).

Table 1 shows the functionality supported by the members of the MPC850 family.

Table 1. MPC850 Functionality Matrix

Part	Number of SCCs Supported	Ethernet Support	ATM Support	USB Support	Multi-channel HDLC Support	Number of PCMCIA Slots Supported
MPC850	1	Yes	-	Yes	-	1
MPC850DE	2	Yes	-	Yes	-	1
MPC850SR	2	Yes	Yes	Yes	Yes	1
MPC850DSL	2	Yes	Yes	Yes	No	1

Additional documentation may be provided for parts listed in Table 1.

  - 2-Kbyte instruction cache and 1-Kbyte data cache (Harvard architecture)
    - Caches are two-way, set-associative
    - Physically addressed
    - Cache blocks can be updated with a 4-word line burst
    - Least-recently used (LRU) replacement algorithm
    - Lockable one-line granularity
  - Memory management units (MMUs) with 8-entry translation lookaside buffers (TLBs) and fully-associative instruction and data TLBs
  - MMUs support multiple page sizes of 4 Kbytes, 16 Kbytes, 256 Kbytes, 512 Kbytes, and 8 Mbytes; 16 virtual address spaces and eight protection groups
- Advanced on-chip emulation debug mode
- Data bus dynamic bus sizing for 8, 16, and 32-bit buses
  - Supports traditional 68000 big-endian, traditional x86 little-endian and modified little-endian memory systems
  - Twenty-six external address lines
- Completely static design (0–80 MHz operation)
- System integration unit (SIU)
  - Hardware bus monitor
  - Spurious interrupt monitor
  - Software watchdog
  - Periodic interrupt timer
  - Low-power stop mode
  - Clock synthesizer
  - Decrementer, time base, and real-time clock (RTC) from the PowerPC architecture
  - Reset controller
  - IEEE 1149.1 test access port (JTAG)
- Memory controller (eight banks)
  - Glueless interface to DRAM single in-line memory modules (SIMMs), synchronous DRAM (SDRAM), static random-access memory (SRAM), electrically programmable read-only memory (EPROM), flash EPROM, etc.
  - Memory controller programmable to support most size and speed memory interfaces
  - Boot chip-select available at reset (options for 8, 16, or 32-bit memory)
  - Variable block sizes, 32 Kbytes to 256 Mbytes
  - Selectable write protection
  - On-chip bus arbiter supports one external bus master
  - Special features for burst mode support
- General-purpose timers
  - Four 16-bit timers or two 32-bit timers

  - Gate mode can enable/disable counting
  - Interrupt can be masked on reference match and event capture
- Interrupts
  - Eight external interrupt request (IRQ) lines
  - Twelve port pins with interrupt capability
  - Fifteen internal interrupt sources
  - Programmable priority among SCCs and USB
  - Programmable highest-priority request
- Single socket PCMCIA-ATA interface
  - Master (socket) interface, release 2.1 compliant
  - Single PCMCIA socket
  - Supports eight memory or I/O windows
- Communications processor module (CPM)
  - 32-bit, Harvard architecture, scalar RISC communications processor (CP)
  - Protocol-specific command sets (for example, GRACEFUL STOP TRANSMIT stops transmission after the current frame is finished or immediately if no frame is being sent and CLOSE RXBD closes the receive buffer descriptor)
  - Supports continuous mode transmission and reception on all serial channels
  - Up to 8 Kbytes of dual-port RAM
  - Twenty serial DMA (SDMA) channels for the serial controllers, including eight for the four USB endpoints
  - Three parallel I/O registers with open-drain capability
- Four independent baud-rate generators (BRGs)
  - Can be connected to any SCC, SMC, or USB
  - Allow changes during operation
  - Autobaud support option
- Two SCCs (serial communications controllers)
  - Ethernet/IEEE 802.3, supporting full 10-Mbps operation
  - HDLC/SDLC™ (all channels supported at 2 Mbps)
  - HDLC bus (implements an HDLC-based local area network (LAN))
  - Asynchronous HDLC to support PPP (point-to-point protocol)
  - AppleTalk®
  - Universal asynchronous receiver transmitter (UART)
  - Synchronous UART
  - Serial infrared (IrDA)
  - Totally transparent (bit streams)
  - Totally transparent (frame based with optional cyclic redundancy check (CRC))

Table 5. DC Electrical Specifications (continued)

Characteristic	Symbol	Min	Max	Unit
Input low voltage	VIL	GND	0.8	V
EXTAL, EXTCLK input high voltage	VIHC	0.7*(VCC)	VCC+0.3	V
Input leakage current, Vin = 5.5 V (Except TMS, TRST, DSCK and DSDI pins)	I_{in}	—	100	µA
Input leakage current, Vin = 3.6V (Except TMS, TRST, DSCK and DSDI pins)	I_{In}	—	10	µA
Input leakage current, Vin = 0V (Except TMS, TRST, DSCK and DSDI pins)	I_{In}	—	10	µA
Input capacitance	C_{in}	—	20	pF
Output high voltage, IOH = -2.0 mA, VDDH = 3.0V except XTAL, XFC, and open-drain pins	VOH	2.4	—	V
Output low voltage CLKOUT [3] IOL = 3.2 mA [1] IOL = 5.3 mA [2] IOL = 7.0 mA PA[14]/USBOE, PA[12]/TXD2 IOL = 8.9 mA TS, TA, TEA, BI, BB, HRESET, SRESET	VOL	—	0.5	V

1 A[6:31], TSIZ0/REG, TSIZ1, D[0:31], DP[0:3]/IRQ[3:6], RD/WR, BURST, RSV/IRQ2, IP_B[0:1]/IWP[0:1]/VFLS[0:1], IP_B2/IOIS16_B/AT2, IP_B3/IWP2/VF2, IP_B4/LWP0/VF0, IP_B5/LWP1/VF1, IP_B6/DSDI/AT0, IP_B7/PTR/AT3, PA[15]/USBRXD, PA[13]/RXD2, PA[9]/L1TXDA/SMRXD2, PA[8]/L1RXDA/SMTXD2, PA[7]/CLK1/TIN1/L1RCLKA/BRGO1, PA[6]/CLK2/TOUT1/TIN3, PA[5]/CLK3/TIN2/L1TCLKA/BRGO2, PA[4]/CLK4/TOUT2/TIN4, PB[31]/SPISEL, PB[30]/SPICLK/TXD3, PB[29]/SPIMOSI /RXD3, PB[28]/SPIMISO/BRGO3, PB[27]/I2CSDA/BRGO1, PB[26]/I2CSCL/BRGO2, PB[25]/SMTXD1/TXD3, PB[24]/SMRXD1/RXD3, PB[23]/SMSYN1/SDACK1, PB[22]/SMSYN2/SDACK2, PB[19]/L1ST1, PB[18]/RTS2/L1ST2, PB[17]/L1ST3, PB[16]/L1RQa/L1ST4, PC[15]/DREQ0/L1ST5, PC[14]/DREQ1/RTS2/L1ST6, PC[13]/L1ST7/RTS3, PC[12]/L1RQa/L1ST8, PC[11]/USBRXP, PC[10]/TGATE1/USBRXN, PC[9]/CTS2, PC[8]/CD2/TGATE1, PC[7]/USBTXP, PC[6]/USBTXN, PC[5]/CTS3/L1TSYNCA/SDACK1, PC[4]/CD3/L1RSYNCA, PD[15], PD[14], PD[13], PD[12], PD[11], PD[10], PD[9], PD[8], PD[7], PD[6], PD[5], PD[4], PD[3]

2 BDIP/GPL_B5, BR, BG, FRZ/IRQ6, CS[0:5], CS6/CE1_B, CS7/CE2_B, WE0/BS_AB0/IORD, WE1/BS_AB1/IOWR, WE2/BS_AB2/PCOE, WE3/BS_AB3/PCWE, GPL_A0/GPL_B0, OE/GPL_A1/GPL_B1, GPL_A[2:3]/GPL_B[2:3]/CS[2:3], UPWAITA/GPL_A4/AS, UPWAITB/GPL_B4, GPL_A5, ALE_B/DSCK/AT1, OP2/MODCK1/STS, OP3/MODCK2/DSDO

3 The MPC850 IBIS model must be used to accurately model the behavior of the Clkout output driver for the full and half drive setting. Due to the nature of the Clkout output buffer, IOH and IOL for Clkout should be extracted from the IBIS model at any output voltage level.

5 Power Considerations

The average chip-junction temperature, T_J, in °C can be obtained from the equation:

$T_J = T_A + (P_D \bullet \theta_{JA})(1)$

where

T_A = Ambient temperature, °C

Table 6. Bus Operation Timing [1] (continued)

Num	Characteristic	50 MHz		66 MHz		80 MHz		FFACT	Cap Load (default 50 pF)	Unit
		Min	Max	Min	Max	Min	Max			
B22	CLKOUT rising edge to $\overline{CS}$ asserted GPCM ACS = 00	5.00	11.75	7.58	14.33	6.25	13.00	0.250	50.00	ns
B22a	CLKOUT falling edge to $\overline{CS}$ asserted GPCM ACS = 10, TRLX = 0,1	—	8.00	—	8.00	—	8.00	—	50.00	ns
B22b	CLKOUT falling edge to $\overline{CS}$ asserted GPCM ACS = 11, TRLX = 0, EBDF = 0	5.00	11.75	7.58	14.33	6.25	13.00	0.250	50.00	ns
B22c	CLKOUT falling edge to $\overline{CS}$ asserted GPCM ACS = 11, TRLX = 0, EBDF = 1	7.00	14.00	11.00	18.00	9.00	16.00	0.375	50.00	ns
B23	CLKOUT rising edge to $\overline{CS}$ negated GPCM read access, GPCM write access ACS = 00, TRLX = 0 & CSNT = 0	2.00	8.00	2.00	8.00	2.00	8.00	—	50.00	ns
B24	A[6–31] to $\overline{CS}$ asserted GPCM ACS = 10, TRLX = 0.	3.00	—	6.00	—	4.00	—	0.250	50.00	ns
B24a	A[6–31] to $\overline{CS}$ asserted GPCM ACS = 11, TRLX = 0	8.00	—	13.00	—	11.00	—	0.500	50.00	ns
B25	CLKOUT rising edge to $\overline{OE}$, $\overline{WE[0–3]}$ asserted	—	9.00	—	9.00	—	9.00	—	50.00	ns
B26	CLKOUT rising edge to $\overline{OE}$ negated	2.00	9.00	2.00	9.00	2.00	9.00	—	50.00	ns
B27	A[6–31] to $\overline{CS}$ asserted GPCM ACS = 10, TRLX = 1	23.00	—	36.00	—	29.00	—	1.250	50.00	ns
B27a	A[6–31] to $\overline{CS}$ asserted GPCM ACS = 11, TRLX = 1	28.00	—	43.00	—	36.00	—	1.500	50.00	ns
B28	CLKOUT rising edge to $\overline{WE[0–3]}$ negated GPCM write access CSNT = 0	—	9.00	—	9.00	—	9.00	—	50.00	ns
B28a	CLKOUT falling edge to $\overline{WE[0–3]}$ negated GPCM write access TRLX = 0,1 CSNT = 1, EBDF = 0	5.00	12.00	8.00	14.00	6.00	13.00	0.250	50.00	ns
B28b	CLKOUT falling edge to $\overline{CS}$ negated GPCM write access TRLX = 0,1 CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	—	12.00	—	14.00	—	13.00	0.250	50.00	ns

Table 6. Bus Operation Timing [1] (continued)

Num	Characteristic	50 MHz		66 MHz		80 MHz		FFACT	Cap Load (default 50 pF)	Unit
		Min	Max	Min	Max	Min	Max			
B28c	CLKOUT falling edge to $\overline{\text{WE[0–3]}}$ negated GPCM write access TRLX = 0,1 CSNT = 1 write access TRLX = 0, CSNT = 1, EBDF = 1	7.00	14.00	11.00	18.00	9.00	16.00	0.375	50.00	ns
B28d	CLKOUT falling edge to $\overline{\text{CS}}$ negated GPCM write access TRLX = 0,1 CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	—	14.00	—	18.00	—	16.00	0.375	50.00	ns
B29	$\overline{\text{WE[0–3]}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access, CSNT = 0	3.00	—	6.00	—	4.00	—	0.250	50.00	ns
B29a	$\overline{\text{WE[0–3]}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 0 CSNT = 1, EBDF = 0	8.00	—	13.00	—	11.00	—	0.500	50.00	ns
B29b	$\overline{\text{CS}}$ negated to D[0–31], DP[0–3], high-Z GPCM write access, ACS = 00, TRLX = 0 & CSNT = 0	3.00	—	6.00	—	4.00	—	0.250	50.00	ns
B29c	$\overline{\text{CS}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	8.00	—	13.00	—	11.00	—	0.500	50.00	ns
B29d	$\overline{\text{WE[0–3]}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 1, CSNT = 1, EBDF = 0	28.00	—	43.00	—	36.00	—	1.500	50.00	ns
B29e	$\overline{\text{CS}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	28.00	—	43.00	—	36.00	—	1.500	50.00	ns
B29f	$\overline{\text{WE[0–3]}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access TRLX = 0, CSNT = 1, EBDF = 1	5.00	—	9.00	—	7.00	—	0.375	50.00	ns
B29g	$\overline{\text{CS}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	5.00	—	9.00	—	7.00	—	0.375	50.00	ns

Table 6. Bus Operation Timing [1] (continued)

Num	Characteristic	50 MHz		66 MHz		80 MHz		FFACT	Cap Load (default 50 pF)	Unit
		Min	Max	Min	Max	Min	Max			
B29h	$\overline{WE}$[0–3] negated to D[0–31], DP[0–3] high-Z GPCM write access TRLX = 0, CSNT = 1, EBDF = 1	25.00	—	39.00	—	31.00	—	1.375	50.00	ns
B29i	$\overline{CS}$ negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	25.00	—	39.00	—	31.00	—	1.375	50.00	ns
B30	$\overline{CS}$, $\overline{WE}$[0–3] negated to A[6–31] invalid GPCM write access [9]	3.00	—	6.00	—	4.00	—	0.250	50.00	ns
B30a	$\overline{WE}$[0–3] negated to A[6–31] invalid GPCM write access, TRLX = 0, CSNT = 1, $\overline{CS}$ negated to A[6–31] invalid GPCM write access TRLX = 0, CSNT =1, ACS = 10 or ACS = 11, EBDF = 0	8.00	—	13.00	—	11.00	—	0.500	50.00	ns
B30b	$\overline{WE}$[0–3] negated to A[6–31] invalid GPCM write access, TRLX = 1, CSNT = 1. $\overline{CS}$ negated to A[6–31] Invalid GPCM write access TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	28.00	—	43.00	—	36.00	—	1.500	50.00	ns
B30c	$\overline{WE}$[0–3] negated to A[6–31] invalid GPCM write access, TRLX = 0, CSNT = 1. $\overline{CS}$ negated to A[6–31] invalid GPCM write access, TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	5.00	—	8.00	—	6.00	—	0.375	50.00	ns
B30d	$\overline{WE}$[0–3] negated to A[6–31] invalid GPCM write access TRLX = 1, CSNT =1, $\overline{CS}$ negated to A[6–31] invalid GPCM write access TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	25.00	—	39.00	—	31.00	—	1.375	50.00	ns

Table 6. Bus Operation Timing [1] (continued)

Num	Characteristic	50 MHz		66 MHz		80 MHz		FFACT	Cap Load (default 50 pF)	Unit
		Min	Max	Min	Max	Min	Max			
B33a	CLKOUT rising edge to GPL valid - as requested by control bit GxT3 in the corresponding word in the UPM	5.00	12.00	8.00	14.00	6.00	13.00	0.250	50.00	ns
B34	A[6–31] and D[0–31] to $\overline{CS}$ valid - as requested by control bit CST4 in the corresponding word in the UPM	3.00	—	6.00	—	4.00	—	0.250	50.00	ns
B34a	A[6–31] and D[0–31] to $\overline{CS}$ valid - as requested by control bit CST1 in the corresponding word in the UPM	8.00	—	13.00	—	11.00	—	0.500	50.00	ns
B34b	A[6–31] and D[0–31] to $\overline{CS}$ valid - as requested by CST2 in the corresponding word in UPM	13.00	—	21.00	—	17.00	—	0.750	50.00	ns
B35	A[6–31] to $\overline{CS}$ valid - as requested by control bit BST4 in the corresponding word in UPM	3.00	—	6.00	—	4.00	—	0.250	50.00	ns
B35a	A[6–31] and D[0–31] to $\overline{BS}$ valid - as requested by BST1 in the corresponding word in the UPM	8.00	—	13.00	—	11.00	—	0.500	50.00	ns
B35b	A[6–31] and D[0–31] to $\overline{BS}$ valid - as requested by control bit BST2 in the corresponding word in the UPM	13.00	—	21.00	—	17.00	—	0.750	50.00	ns
B36	A[6–31] and D[0–31] to GPL valid - as requested by control bit GxT4 in the corresponding word in the UPM	3.00	—	6.00	—	4.00	—	0.250	50.00	ns
B37	UPWAIT valid to CLKOUT falling edge [10]	6.00	—	6.00	—	6.00	—	—	50.00	ns
B38	CLKOUT falling edge to UPWAIT valid [10]	1.00	—	1.00	—	1.00	—	—	50.00	ns
B39	$\overline{AS}$ valid to CLKOUT rising edge [11]	7.00	—	7.00	—	7.00	—	—	50.00	ns
B40	A[6–31], TSIZ[0–1], RD/$\overline{WR}$, $\overline{BURST}$, valid to CLKOUT rising edge.	7.00	—	7.00	—	7.00	—	—	50.00	ns
B41	$\overline{TS}$ valid to CLKOUT rising edge (setup time)	7.00	—	7.00	—	7.00	—	—	50.00	ns

Figure 4 provides the timing for the synchronous output signals.

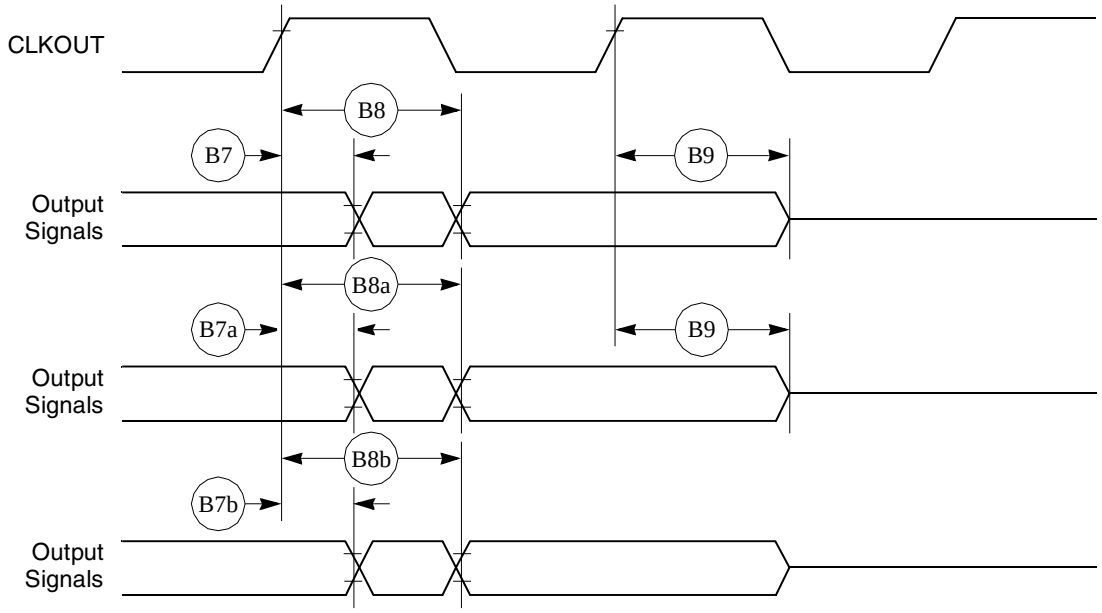


Figure 4. Synchronous Output Signals Timing

Figure 5 provides the timing for the synchronous active pull-up and open-drain output signals.

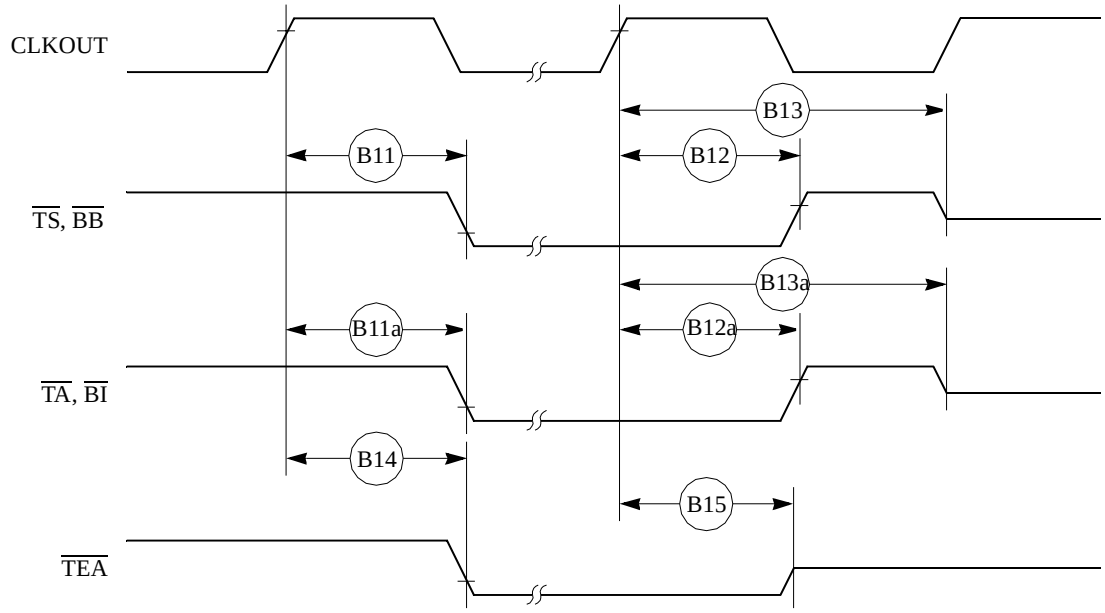


Figure 5. Synchronous Active Pullup and Open-Drain Outputs Signals Timing

Figure 8 provides the timing for the input data controlled by the UPM in the memory controller.

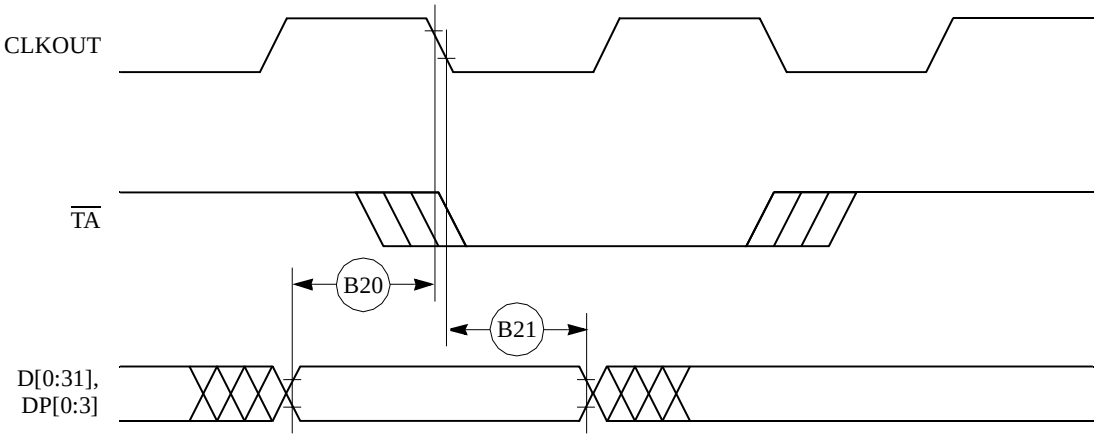


Figure 8. Input Data Timing when Controlled by UPM in the Memory Controller

Figure 9 through Figure 12 provide the timing for the external bus read controlled by various GPCM factors.

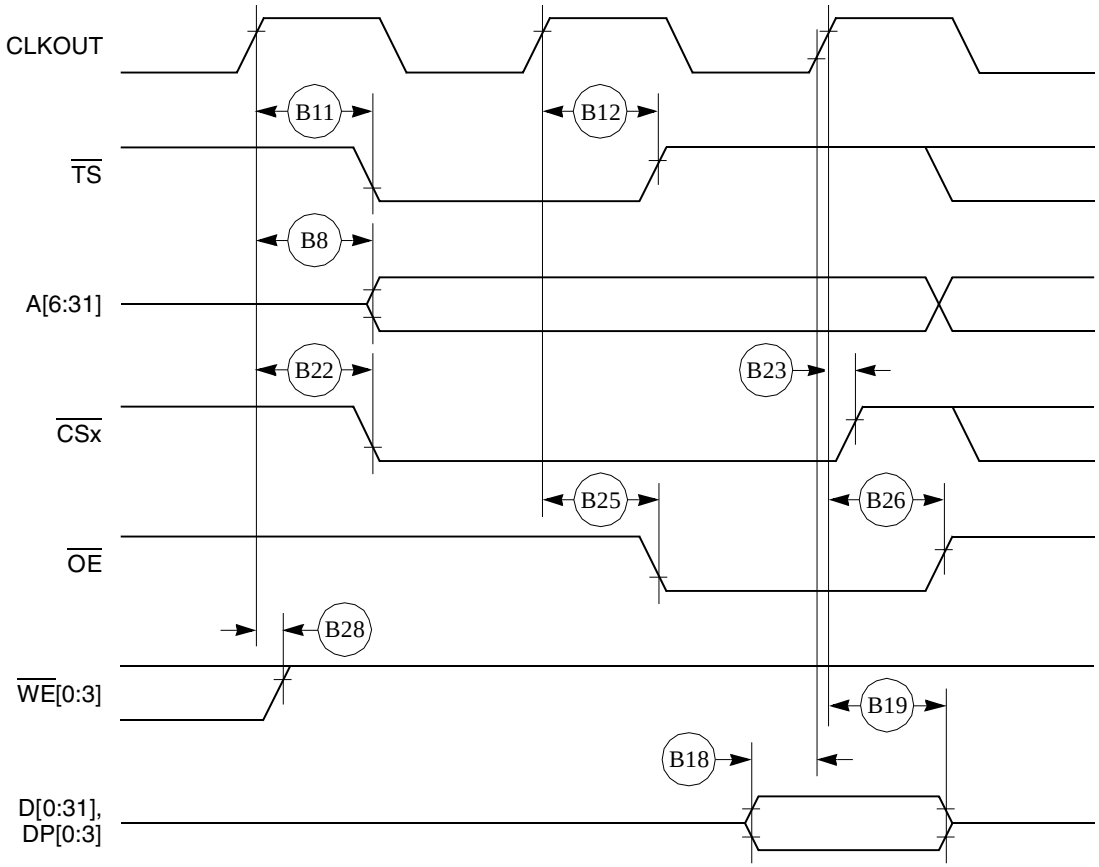


Figure 9. External Bus Read Timing (GPCM Controlled—ACS = 00)

Table 8 shows the PCMCIA timing for the MPC850.

Table 8. PCMCIA Timing

Num	Characteristic	50MHz		66MHz		80 MHz		FFACTOR	Unit
		Min	Max	Min	Max	Min	Max		
P44	A[6–31], REG valid to PCMCIA strobe asserted. [1]	13.00	—	21.00	—	17.00	—	0.750	ns
P45	A[6–31], REG valid to ALE negation.[1]	18.00	—	28.00	—	23.00	—	1.000	ns
P46	CLKOUT to REG valid	5.00	13.00	8.00	16.00	6.00	14.00	0.250	ns
P47	CLKOUT to REG Invalid.	6.00	—	9.00	—	7.00	—	0.250	ns
P48	CLKOUT to CE1, CE2 asserted.	5.00	13.00	8.00	16.00	6.00	14.00	0.250	
P49	CLKOUT to CE1, CE2 negated.	5.00	13.00	8.00	16.00	6.00	14.00	0.250	ns
P50	CLKOUT to PCOE, IORD, PCWE, IOWR assert time.	—	11.00	—	11.00	—	11.00	—	ns
P51	CLKOUT to PCOE, IORD, PCWE, IOWR negate time.	2.00	11.00	2.00	11.00	2.00	11.00	—	ns
P52	CLKOUT to ALE assert time	5.00	13.00	8.00	16.00	6.00	14.00	0.250	ns
P53	CLKOUT to ALE negate time	—	13.00	—	16.00	—	14.00	0.250	ns
P54	PCWE, IOWR negated to D[0–31] invalid.[1]	3.00	—	6.00	—	4.00	—	0.250	ns
P55	WAIT_B valid to CLKOUT rising edge.[1]	8.00	—	8.00	—	8.00	—	—	ns
P56	CLKOUT rising edge to WAIT_B invalid.[1]	2.00	—	2.00	—	2.00	—	—	ns

[1] PSST = 1. Otherwise add PSST times cycle time.
PSHT = 0. Otherwise add PSHT times cycle time.

These synchronous timings define when the WAIT_B signal is detected in order to freeze (or relieve) the PCMCIA current cycle. The WAIT_B assertion will be effective only if it is detected 2 cycles before the PSL timer expiration. See PCMCIA Interface in the MPC850 PowerQUICC User's Manual.

Table 9 shows the PCMCIA port timing for the MPC850.

Table 9. PCMCIA Port Timing

Num	Characteristic	50 MHz		66 MHz		80 MHz		Unit
		Min	Max	Min	Max	Min	Max	
P57	CLKOUT to OPx valid	—	19.00	—	19.00	—	19.00	ns
P58	$\overline{\text{HRESET}}$ negated to OPx drive [1]	18.00	—	26.00	—	22.00	—	ns
P59	IP_Xx valid to CLKOUT rising edge	5.00	—	5.00	—	5.00	—	ns
P60	CLKOUT rising edge to IP_Xx invalid	1.00	—	1.00	—	1.00	—	ns

[1] OP2 and OP3 only.

Figure 27 provides the PCMCIA output port timing for the MPC850.

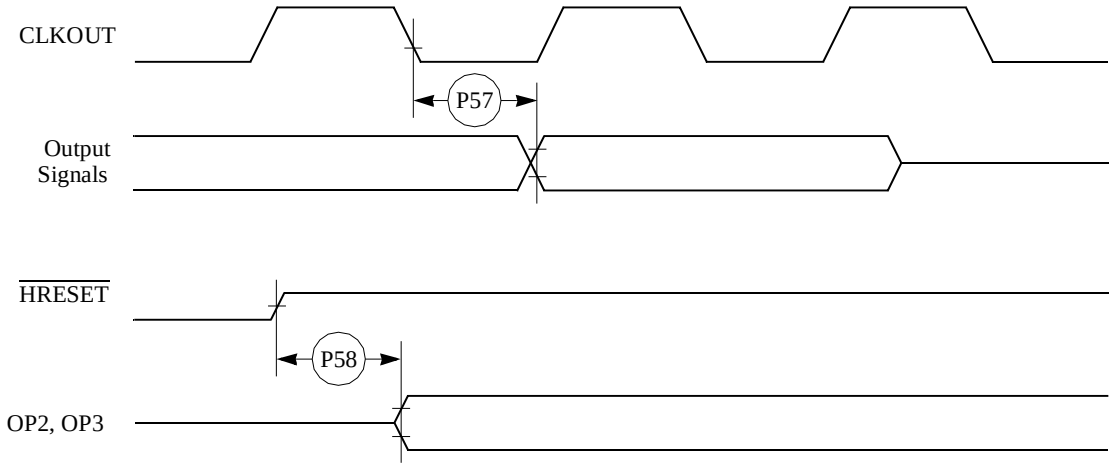


Figure 27. PCMCIA Output Port Timing

Figure 28 provides the PCMCIA output port timing for the MPC850.

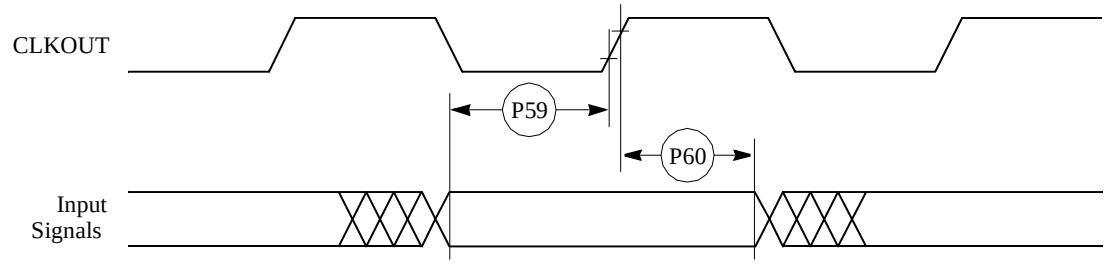


Figure 28. PCMCIA Input Port Timing

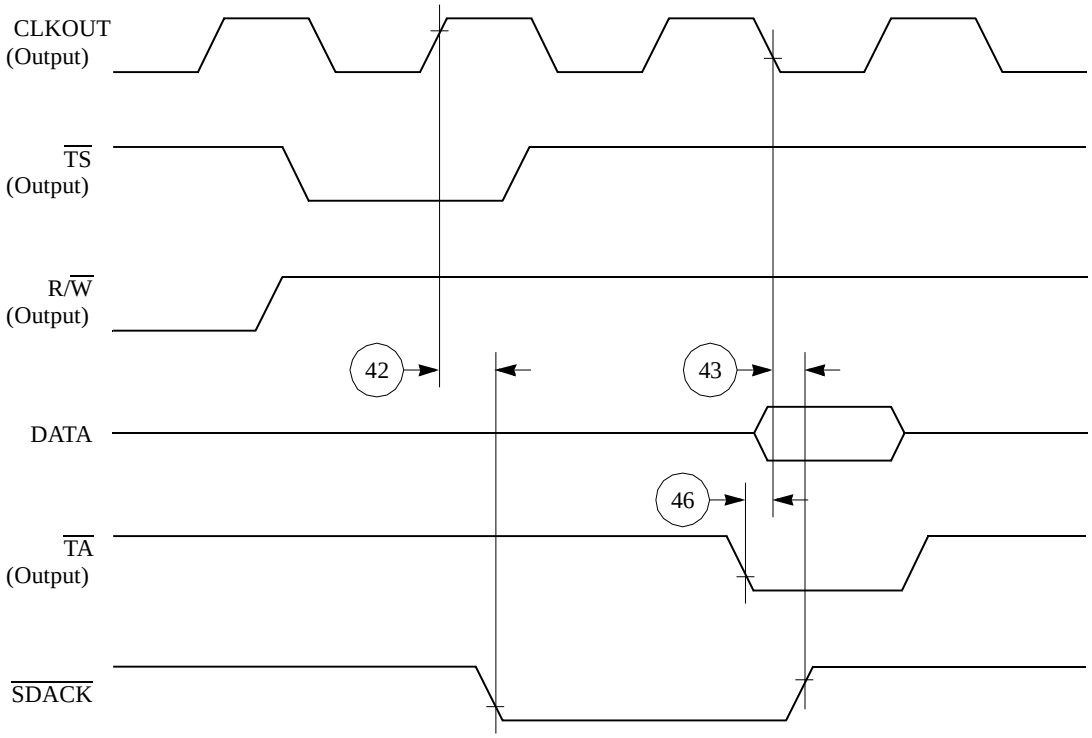


Figure 40. SDACK Timing Diagram—Peripheral Write, TA Sampled Low at the Falling Edge of the Clock

Table 17. SI Timing (continued)

Num	Characteristic	All Frequencies		Unit
		Min	Max	
82	L1RCLK, L1TCLK frequency (DSC =1)	—	16.00 or SYNCCLK/2	MHz
83	L1RCLK, L1TCLK width low (DSC =1)	P + 10	—	ns
83A	L1RCLK, L1TCLK width high (DSC = 1)[3]	P + 10	—	ns
84	L1CLK edge to L1CLKO valid (DSC = 1)	—	30.00	ns
85	$\overline{\text{L1RQ}}$ valid before falling edge of L1TSYNC[4]	1.00	—	L1TCLK
86	L1GR setup time[2]	42.00	—	ns
87	L1GR hold time	42.00	—	ns
88	L1xCLK edge to L1SYNC valid (FSD = 00) CNT = 0000, BYT = 0, DSC = 0)	—	0.00	ns

1 The ratio SyncCLK/L1RCLK must be greater than 2.5/1.

2 These specs are valid for IDL mode only.

3 Where P = 1/CLKOUT. Thus for a 25-MHz CLKO1 rate, P = 40 ns.

4 These strobes and TxD on the first bit of the frame become valid after L1CLK edge or L1SYNC, whichever is later.

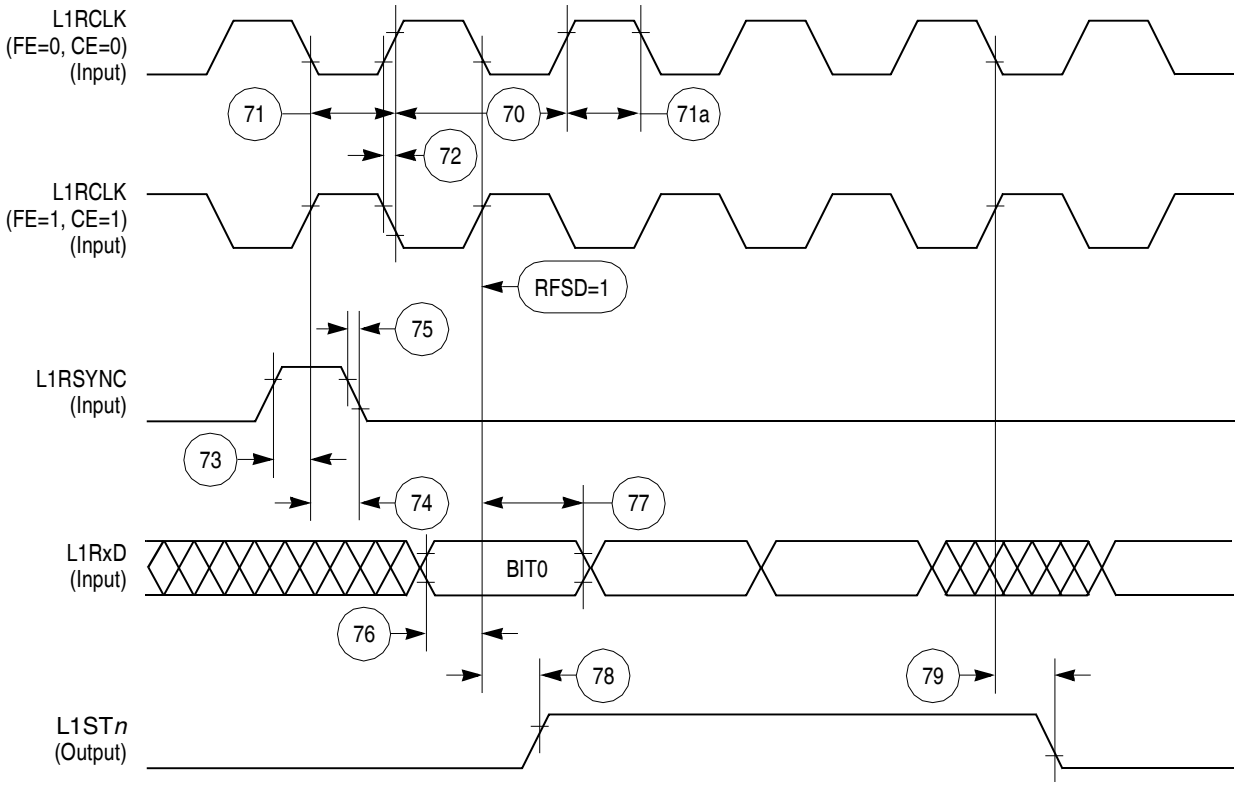


Figure 45. SI Receive Timing Diagram with Normal Clocking (DSC = 0)

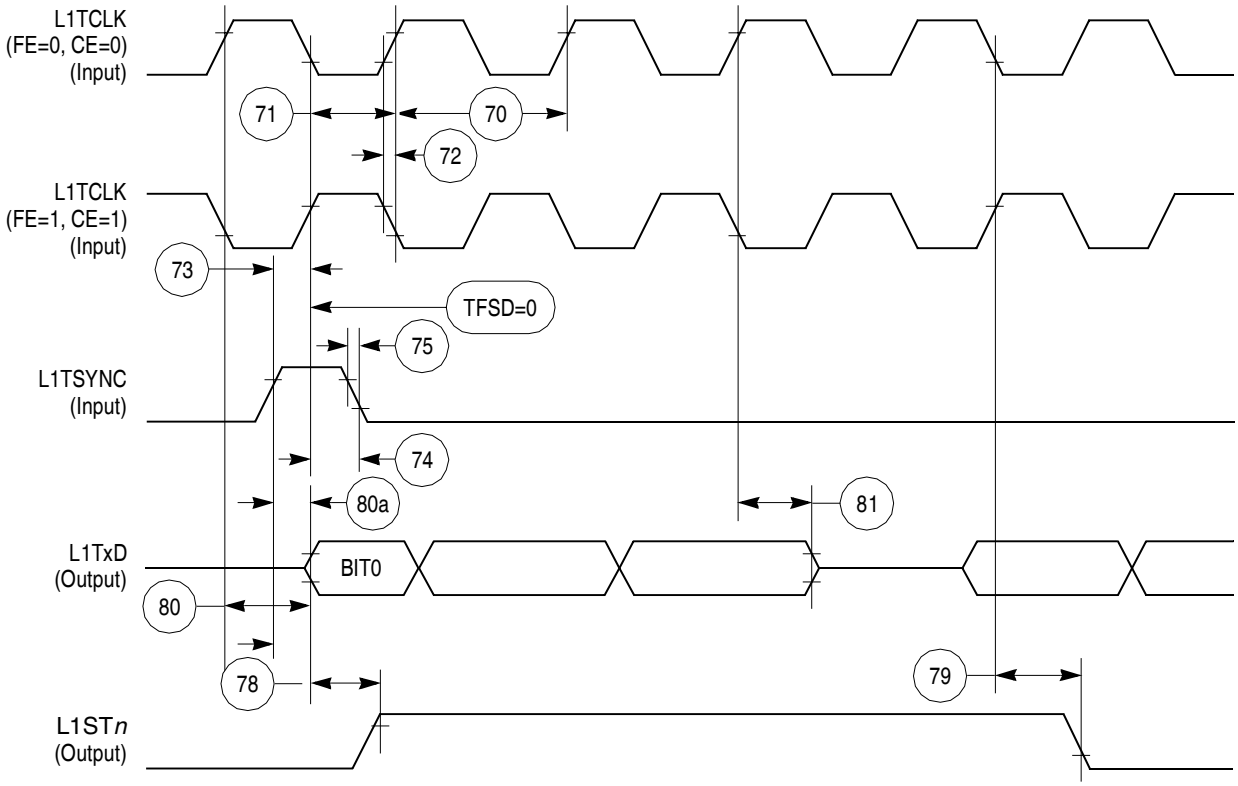


Figure 47. SI Transmit Timing Diagram

8.6 SCC in NMSI Mode Electrical Specifications

Table 18 provides the NMSI external clock timing.

Table 18. NMSI External Clock Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
100	RCLKx and TCLKx frequency [1] (x = 2, 3 for all specs in this table)	1/SYNCCLK	—	ns
101	RCLKx and TCLKx width low	1/SYNCCLK +5	—	ns
102	RCLKx and TCLKx rise/fall time	—	15.00	ns
103	TXDx active delay (from TCLKx falling edge)	0.00	50.00	ns
104	$\overline{\text{RTSx}}$ active/inactive delay (from TCLKx falling edge)	0.00	50.00	ns
105	$\overline{\text{CTSx}}$ setup time to TCLKx rising edge	5.00	—	ns
106	RXDx setup time to RCLKx rising edge	5.00	—	ns
107	RXDx hold time from RCLKx rising edge [2]	5.00	—	ns
108	$\overline{\text{CDx}}$ setup time to RCLKx rising edge	5.00	—	ns

1 The ratios SyncCLK/RCLKx and SyncCLK/TCLKx must be greater than or equal to 2.25/1.

2 Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as an external sync signal.

Table 19 provides the NMSI internal clock timing.

Table 19. NMSI Internal Clock Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
100	RCLKx and TCLKx frequency [1] (x = 2, 3 for all specs in this table)	0.00	SYNCCLK/3	MHz
102	RCLKx and TCLKx rise/fall time	—	—	ns
103	TXDx active delay (from TCLKx falling edge)	0.00	30.00	ns
104	$\overline{\text{RTSx}}$ active/inactive delay (from TCLKx falling edge)	0.00	30.00	ns
105	$\overline{\text{CTSx}}$ setup time to TCLKx rising edge	40.00	—	ns
106	RXDx setup time to RCLKx rising edge	40.00	—	ns
107	RXDx hold time from RCLKx rising edge [2]	0.00	—	ns
108	$\overline{\text{CDx}}$ setup time to RCLKx rising edge	40.00	—	ns

1 The ratios SyncCLK/RCLKx and SyncCLK/TCLK1x must be greater or equal to 3/1.

2 Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as an external sync signals.

Table 20. Ethernet Timing (continued)

Num	Characteristic	All Frequencies		Unit
		Min	Max	
134	TENA inactive delay (from TCLKx rising edge)	10.00	50.00	ns
138	CLKOUT low to $\overline{\text{SDACK}}$ asserted [2]	—	20.00	ns
139	CLKOUT low to $\overline{\text{SDACK}}$ negated [2]	—	20.00	ns

1 The ratios SyncCLK/RCLKx and SyncCLK/TCLKx must be greater or equal to 2/1.

2 $\overline{\text{SDACK}}$ is asserted whenever the SDMA writes the incoming frame destination address into memory.

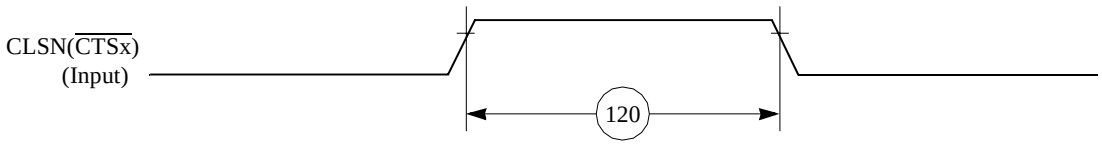


Figure 53. Ethernet Collision Timing Diagram

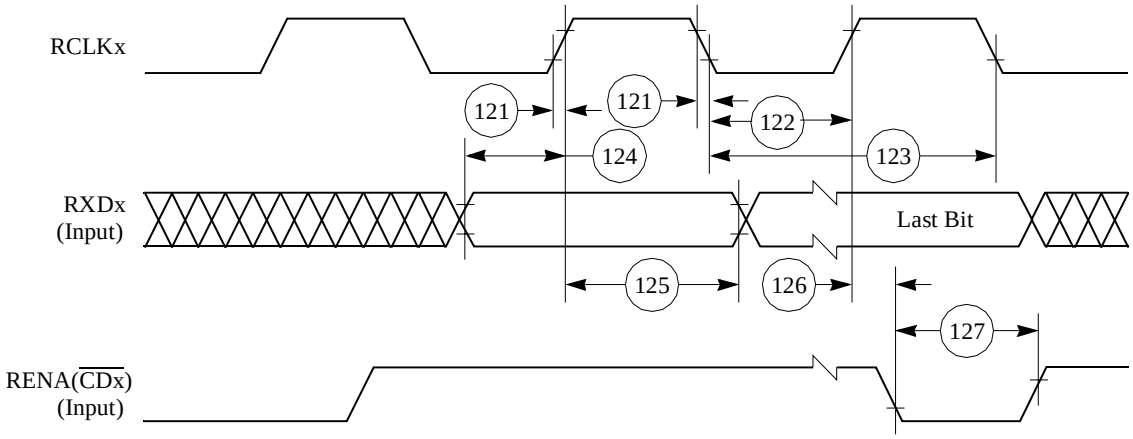
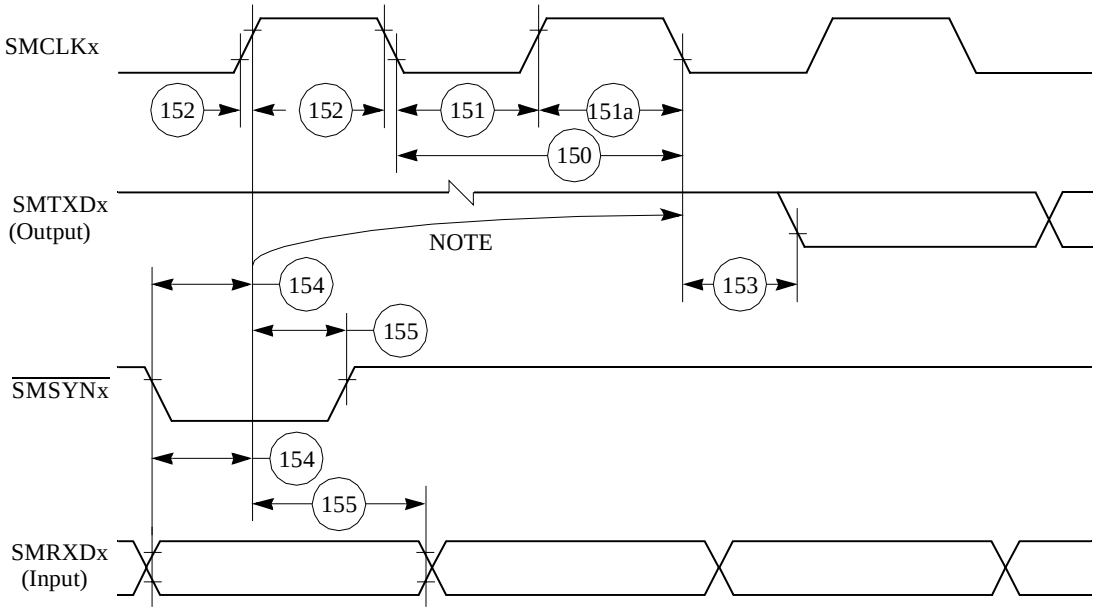


Figure 54. Ethernet Receive Timing Diagram



NOTE:
1. This delay is equal to an integer number of character-length clocks.

Figure 56. SMC Transparent Timing Diagram

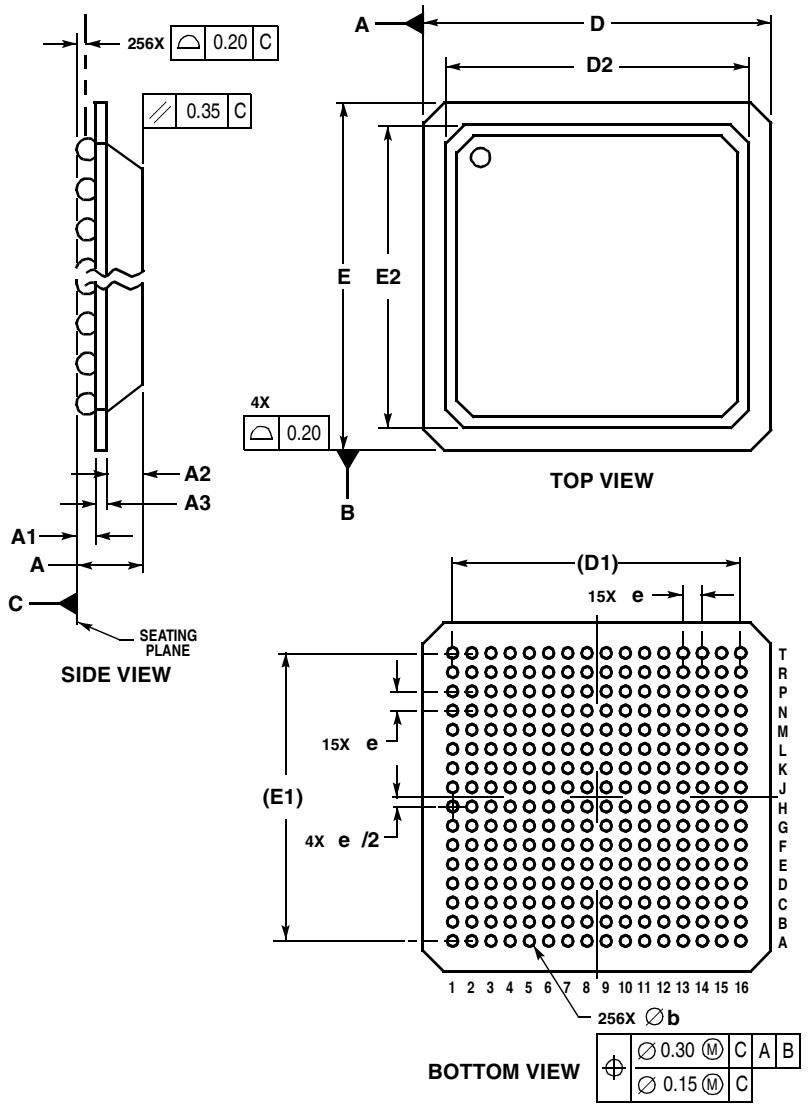
8.9 SPI Master AC Electrical Specifications

Table 22 provides the SPI master timings as shown in Figure 57 and Figure 58.

Table 22. SPI Master Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
160	MASTER cycle time	4	1024	t_{cyc}
161	MASTER clock (SCK) high or low time	2	512	t_{cyc}
162	MASTER data setup time (inputs)	50.00	—	ns
163	Master data hold time (inputs)	0.00	—	ns
164	Master data valid (after SCK edge)	—	20.00	ns
165	Master data hold time (outputs)	0.00	—	ns
166	Rise time output	—	15.00	ns
167	Fall time output	—	15.00	ns

Figure 64 shows the non-JEDEC package dimensions of the PBGA.



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS IN MILLIMETERS.
3. DIMENSION b IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER, PARALLEL TO PRIMARY DATUM C.
4. PRIMARY DATUM C AND THE SEATING PLANE ARE

	MILLIMETERS	
DIM	MIN	MAX
A	1.91	2.35
A1	0.50	0.70
A2	1.12	1.22
A3	0.29	0.43
b	0.60	0.90
D	23.00 BSC	
D1	19.05 REF	
D2	19.00	20.00
E	23.00 BSC	
E1	19.05 REF	
E2	19.00	20.00
e	1.27 BSC	

Figure 64. Package Dimensions for the Plastic Ball Grid Array (PBGA)—non-JEDEC Standard

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